

#### ESD5B5CM

Low Capacitance Bidirectional TVS/ESD Protection Diode

## DESCRIPTION

The ESD5B5CM is designed to protect voltage sensitive components from ESD and transient voltage events. Ex -cellent clamping capability, low leakage, and fast respon -se time, make these parts ideal for ESD protection on d -esigns where board space is at a premium. Because of its small size, it is suited for use in cellular phones, porta -ble devices, digital cameras, power supplies and many other portable applications where board space comes at a premium. Also because of its low capacitance, it is sui -ted for use in high frequency designs such as USB 2.0 high speed, VGA, DVI, SDI and other high speed line ap -plications.

This device has been specifically designed to protect se -nsitive components which are connected to data and tra -nsmission lines from overvoltage caused by ESD(electr -ostatic discharge), and EFT (electrical fast transients).

#### **FEATURES**

- ♦ IEC61000-4-2 (ESD) ±15kV (air), ±8kV (contact).
- → IEC61000-4-4 (EFT) 40A (5/50ns).
- Peak power dissipation: 400W (8/20μs).
- Protects one directional I/O line.
- Low clamping voltage.
- ♦ Working voltages : 5V.
- Low leakage current.
- Low capacitance.

Http://www.jksemi.com ESD5B5CM





# **APPLICATIONS**

- ♦ High Speed Line :USB1.0/2.0, VGA, DVI, SDI.
- ♦ Serial and Parallel Ports.
- ♦ Notebooks, Desktops, Servers.
- ♦ Projection TV.
- ♦ Cellular handsets and accessories.
- ♦ Portable instrumentation.
- ♦ Peripherals.

# **ORDERING INFORMATIO**

♦ Device: ESD5B5CM.

♦ Package: SOD-523.

♦ Material: Halogen free.

♦ Packing: Tape & Reel.

♦ Quantity per reel: 3,000pcs.

#### MECHANICAL CHARACTERISTICS

♦ SOD-523 package.

♦ Terminals: Gold plated, solderable per MIL-

STD-750, method 2026.

♦ Packaging: Tape and Reel.

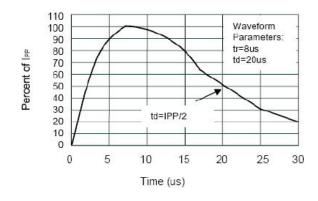
## DEVICE CHARACTERISTICS

ABSOLUTE MAXIMUM RATING(T <sub>A</sub> =25°C unless otherwise specified)						
Symbol	ymbol Parameter		Units			
V <sub>ESD</sub>	ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	±15 ±8	kV			
P <sub>PP</sub>	Peak Pulse Power (8/20µs)	400	W			
T <sub>OPT</sub>	T <sub>OPT</sub> Operating Temperature		°C			
T <sub>STG</sub>	Storage Temperature	-55~150	°C			

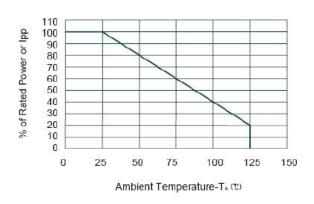


ELECTRICAL CHARACTERISTICS (Tamb=25°C)								
Symbol	Parameter	Test Condition	Min	Тур	Max	Units		
$V_{RWM}$	Reverse Working Voltage				5.0	V		
$V_{BR}$	Reverse Breakdown Voltage	$I_T = 1mA$	5.8		7.8	V		
${ m I}_{ m R}$	Reverse Leakage Current	$V_{RWM} = 5V$			1.0	μΑ		
Vc	Clamping Voltage	$I_{PP} = 1A,$ $t_p = 8/20 \mu s$			9.8	V		
Vc	Clamping Voltage	$I_{PP} = 20A,$ $t_p = 8/20\mu s$		15	20	V		
C₃	Junction Capacitance	$V_R = 0V$ , $f = 1MHz$		30	40	pF		

# **ELECTRICAL CHARACTERISTICS CURVE**



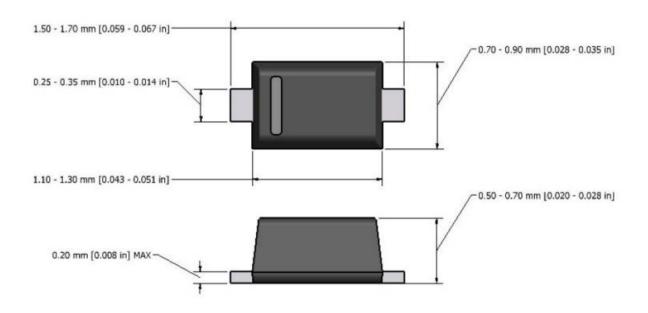
Pulse Waveform



**Power Derating Curve** 



# SOD-523 PACKAGE OUTLINE & DIMENSIONS



Note: Dimensions are exclusive of Burrs, Mold Flash & Tie Bar extrusions.

Website: http://www.jksemi.com
For additional information, please contact your local Sales Representative.

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